1-MSPS, 3.3 V – 4.8 V, ULTRA LOW POWER, 12-BIT SAR ANALOG-TO-DIGITAL CONVERTER

FEATURES

- Single 3.3 V to 4.8 V Supply Operation for XCS7476E
- Fast Throughput Rate:
  1 MSPS for XCS7476E
- ±1.25LSB INL, ±1.25LSB DNL
- No Pipeline Delays
- SPI/DSP/MICROWIRE™/QSPI™ Compatible Serial Interface
- Variable Power Management
- Low Power (XCS7476E Typical):
  2.40mW (3.3 V, 1 MSPS)
  10.0mW (4.5 V, 1 MSPS)
- Second-Source for ADCS7476
- 6-Pin SOT-23 Package

APPLICATIONS

- Battery Powered Systems
- Portable Systems
- Medical Instruments
- Mobile Communications
- Factory Automation and ATM Equipment
- Instrumentation and Control Systems

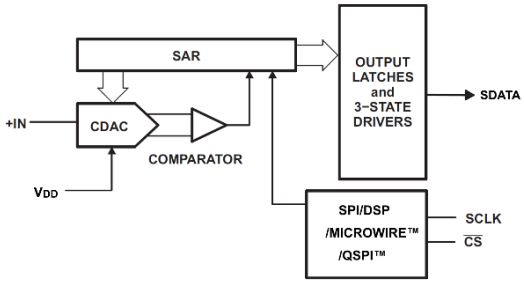


Figure 1. Functional Block Diagram

DESCRIPTION

The XCS7476E is a 12-bit, high speed, low power, and small-sized Successive-Approximation-Register (SAR) ADC. This device can operate from a single 3.3 V to 4.8 V supply with a 1-MSPS throughput.

The XCS7476E is available in a 6-pin SOT-23 package and has an operating temperature range of -40°C to 85°C.

The XCS7476E is a drop-in replacement for the ADCS7476.

SPECIFICATIONS

At-40℃ to 85℃, f_{SAMPLE} = 1 MSPS and f_{SCLK} = 20 MHz if 3.3 V ≤ V_{DD} ≤ 4.8 V. (unless otherwise noted)

PARAMETER	TEST CONDITIONS	XCS7476E			XCS7477E			XCS7478E			UNITS
		MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
SYSTEM PERFORMANCE											
Resolution			**12**			**10**			**8**		Bits
No missing codes			**12**			**10**			**8**		Bits
Integral linearity		**-1.25**		**1.25**	**-1**		**1**	**-0.5**		**0.5**	LSB
Differential linearity		**-1.25**		**1.25**	**-1**		**1**	**-0.5**		**0.5**	LSB
f_{SAMPLE} Throughput rate	f_{SCLK} = 20 MHz, 3.3 V ≤ V_{DD} ≤ 4.8 V			**1**			**1**			**1**	MSPS
SNR	f_{IN} = 100 kHz		**71.5**			**61**			**49**		dB
THD	f_{IN} = 100 kHz		**-84**			**-74**			**-68**		dB

XCS7476E

PARAMETER	TEST CONDITIONS		MIN	TYP	MAX	UNITS
I_{DD} Supply current, normal operation	Digital inputs = 0 V or V_{DD}	f_{SAMPLE} = 1000 KSPS, f_{SCLK} = 20 MHz, V_{DD} = 3.3 V		**0.72**	**1.56**	mA
		f_{SAMPLE} = 1000 KSPS, f_{SCLK} = 20 MHz, V_{DD} = 4.5 V		**2.22**	**3.44**	
		f_{SAMPLE} = 800 KSPS, f_{SCLK} = 16 MHz, V_{DD} = 3.3 V		**0.60**	**1.28**	
		f_{SAMPLE} = 800 KSPS, f_{SCLK} = 16 MHz, V_{DD} = 4.5 V		**1.80**	**2.80**	
POWER DISSIPATION, XCS7476E						
Normal operation		f_{SAMPLE} = 1000 KSPS, f_{SCLK} = 20 MHz, V_{DD} = 3.3 V		**2.40**	**5.15**	mW
		f_{SAMPLE} = 1000 KSPS, f_{SCLK} = 20 MHz, V_{DD} = 4.5 V		**10.0**	**15.5**	mW

PIN CONFIGURATION AND FUNCTION DESCRIPTIONS

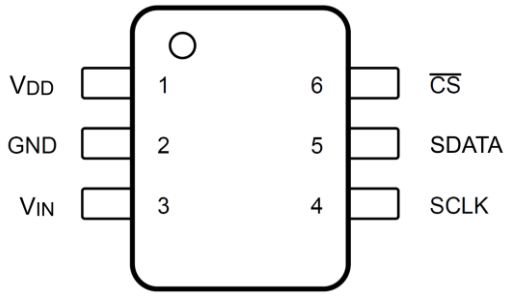


Figure 2. Pin Configuration

TERMINAL		DESCRIPTION
NAME	NO.	
V_{DD}	1	Power Supply Input.
GND	2	The ground return for the supply and signals.
V_{IN}	3	Analog Input. This signal can range from 0 V to V_{DD}.
SCLK	4	Digital clock input. This clock directly controls the conversion and readout processes.
SDATA	5	Digital data output. The output samples are clocked out of this pin on falling edges of the SCLK pin.
$\overline{CS}$	6	Chip Select. On the falling edge of $\overline{CS}$, a conversion process begins.

TYPICAL CONNECTION

Figure 3 shows a typical connection diagram for the XCS7476E. The 4.5 V supply should come from a stable power supply such as an LDO. The supply to XCS7476E should be decoupled to the ground. A 1-µF and a 10-nF decoupling capacitor are required between the V_{DD} and GND pins of the converter. This capacitor should be placed as close as possible to the pins of the device. Always set the V_{DD} supply to be greater than or equal to the maximum input signal to avoid saturation of codes.

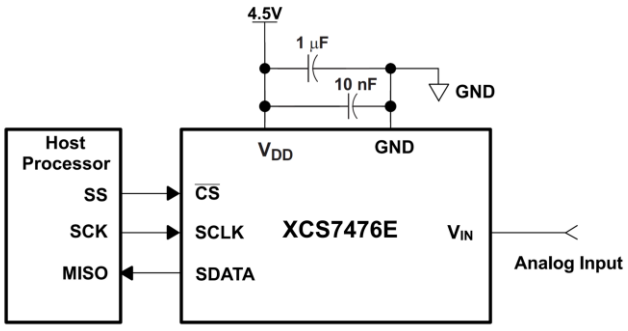


Figure 3. Typical Circuit Configuration

TIMING DIAGRAM

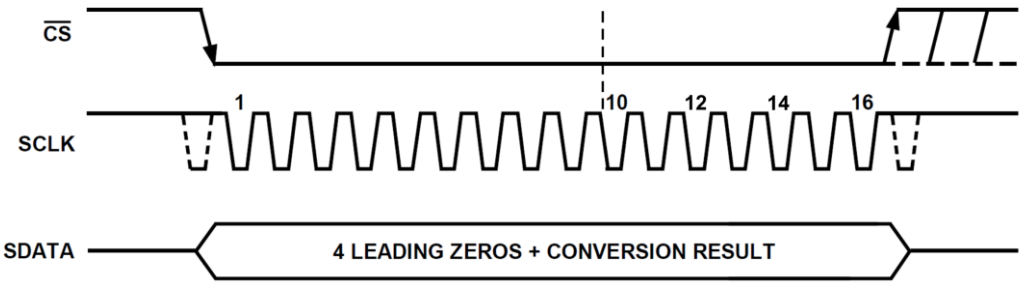


Figure 4. Timing Diagram

The conversion is initiated on the falling edge of $\overline{CS}$. The device outputs data while the conversion is in progress, and it requires 16 serial clock cycles to complete the conversion and access the full results. The XCS7476E data word contains 4 leading zeros, followed by 12-bit data in MSB first format.

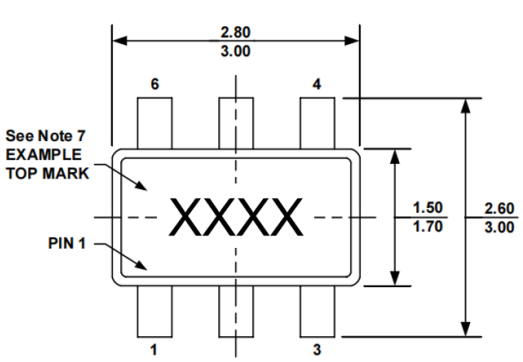
Once a data transfer is complete, SDATA will return to the tri-state mode, and another conversion can be initiated after the quiet time has elapsed by again bringing $\overline{CS}$ low.

POWER-DOWN MODE

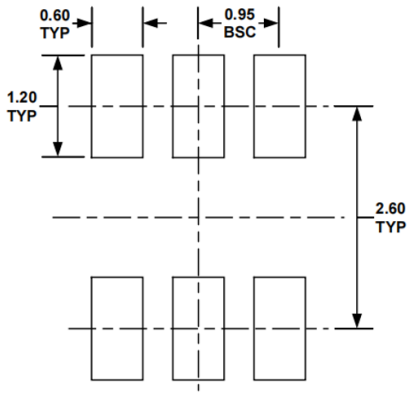
The XCS7476E has an auto power-down feature. Besides powering down all circuitry, the converter consumes only a small amount of current in this mode. The device automatically wakes up when $\overline{CS}$ falls. However, not all of the functional blocks are fully powered until sometime before the third falling edge of SCLK. The device powers down once it reaches the end of conversion which is the 16th falling edge of SCLK for the XCS7476E. The device enters power down mode if $\overline{CS}$ goes high before the 10th SCLK falling edge. Ongoing conversion stops and SDATA goes to three-state under this power down condition.

These converters achieve lower power dissipation for a fixed throughput rate by using higher SCLK frequencies. Higher SCLK frequencies reduce the acquisition time and conversion time. This means the converters spend more time in auto power-down mode per conversion cycle. For a particular SCLK frequency, the acquisition time and conversion time are fixed. Therefore, a lower throughput increases the proportion of the time the converters are in power down, thereby reducing power consumption.

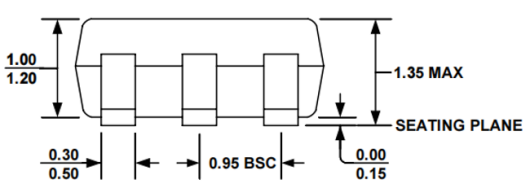
OUTLINE DIMENTIONS



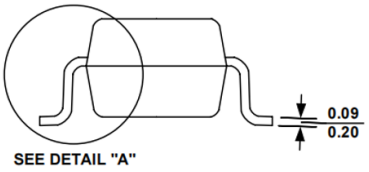
TOP VIEW



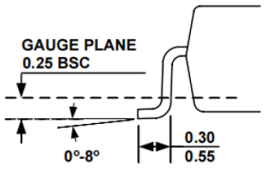
RECOMMENDED LAND PATTERN



FRONT VIEW



SIDE VIEW



DETAIL "A"

NOTE:

1) ALL DIMENSIONS ARE IN MILLIMETERS.
2) PACKAGE LENGTH DOES NOT INCLUDE MOLD FLASH, PROTRUSION OR GATE BURR.
3) PACKAGE WIDTH DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION.
4) LEAD COPLANARITY (BOTTOM OF LEADS AFTER FORMING) SHALL BE 0.10 MILLIMETERS MAX.
5) DRAWING CONFORMS TO JEDEC MO-178, VARIATION AB.
6) DRAWING IS NOT TO SCALE.
7) PIN 1 IS LOWER LEFT PIN WHEN READING TOP MARK FROM LEFT TO RIGHT, (SEE EXAMPLE TOP MARK)

NOTES

1. Unpacked ICs, tube-mounted ICs, etc. must be stored in a drying cabinet, and the humidity in the drying cabinet < 20% R.H.
2. After access, the components are stored in an electrostatic packaging protective bag.
3. Anti-static damage: the device is an electrostatic sensitive device, and sufficient anti-static measures should be taken during transmission, assembly and testing.
4. The user should conduct a visual inspection before use, and the bottom, side and surrounding of the circuit can be welded only if it is bright. If oxidation occurs, the circuit can be processed by means of oxidation, and the circuit must be soldered within 12 hours after processing.